NTF3055-100, NVF3055-100

Power MOSFET 3.0 Amps, 60 Volts N-Channel SOT-223

Designed for low voltage, high speed switching applications in power supplies, converters and power motor controls and bridge circuits.

Features

- NVF Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

Applications

- Power Supplies
- Converters
- Power Motor Controls
- Bridge Circuits

MAXIMUM RATINGS (T_C = 25° C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	60	Vdc
Drain-to-Gate Voltage (R_{GS} = 10 M Ω)	V _{DGR}	60	Vdc
Gate–to–Source Voltage – Continuous – Non–repetitive (t _p ≤ 10 ms)	V _{GS}	± 20 ± 30	Vdc Vpk
$\begin{array}{l} \text{Drain Current} \\ - \text{ Continuous @ } T_{\text{A}} = 25^{\circ}\text{C} \\ - \text{ Continuous @ } T_{\text{A}} = 100^{\circ}\text{C} \\ - \text{ Single Pulse (} t_{p} \leq 10 \ \mu\text{s}) \end{array}$	I _D I _D I _{DM}	3.0 1.4 9.0	Adc Apk
Total Power Dissipation @ $T_A = 25^{\circ}C$ (Note 1) Total Power Dissipation @ $T_A = 25^{\circ}C$ (Note 2) Derate above $25^{\circ}C$	PD	2.1 1.3 0.014	W W W/°C
Operating and Storage Temperature Range	T _J , T _{stg}	-55 to 175	°C
$ Single Pulse Drain-to-Source Avalanche \\ Energy - Starting T_J = 25^{\circ}C \\ (V_{DD} = 25 \text{ Vdc}, V_{GS} = 10 \text{ Vdc}, \\ I_L(pk) = 7.0 \text{ Apk}, L = 3.0 \text{ mH}, V_{DS} = 60 \text{ Vdc}) $	E _{AS}	74	mJ
Thermal Resistance – Junction-to-Ambient (Note 1) – Junction-to-Ambient (Note 2)	$R_{ heta JA} \ R_{ heta JA}$	72.3 114	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	ΤL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. When surface mounted to an FR4 board using 1" pad size, 1 oz. (Cu. Area 1.127 sq in).

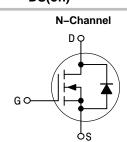
2. When surface mounted to an FR4 board using minimum recommended pad size, 2–2.4 oz. (Cu. Area 0.272 sq in).

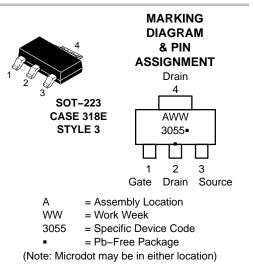


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3.0 A, 60 V R_{DS(on)} = 110 mΩ





ORDERING INFORMATION

Device	Package	Shipping [†]
NTF3055-100T1G	SOT-223 (Pb-Free)	1000 / Tape & Reel
NTF3055-100T3G	SOT-223 (Pb-Free)	4000 / Tape & Reel
NVF3055-100T1G	SOT-223 (Pb-Free)	1000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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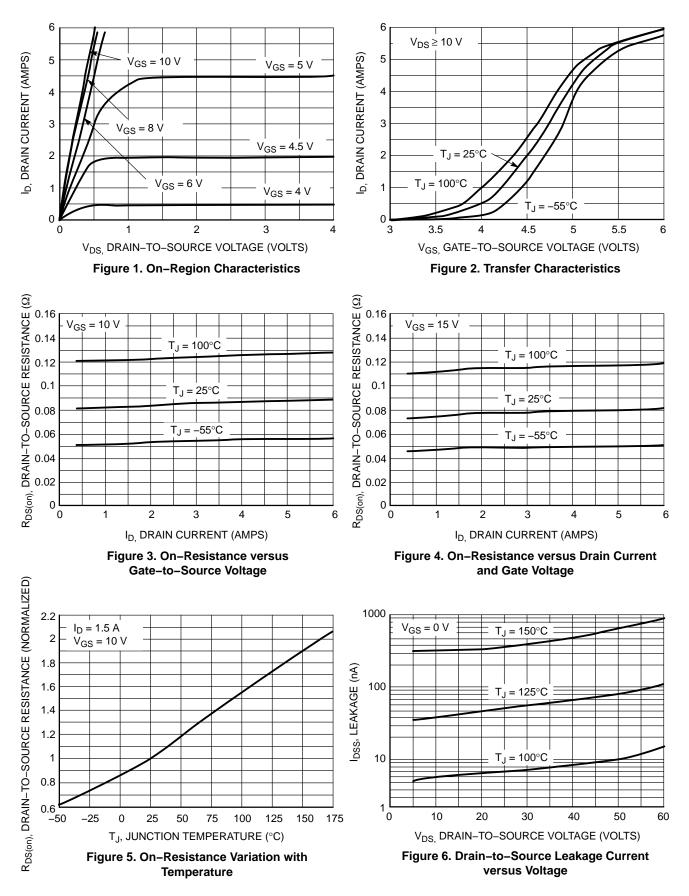
NTF3055-100, NVF3055-100

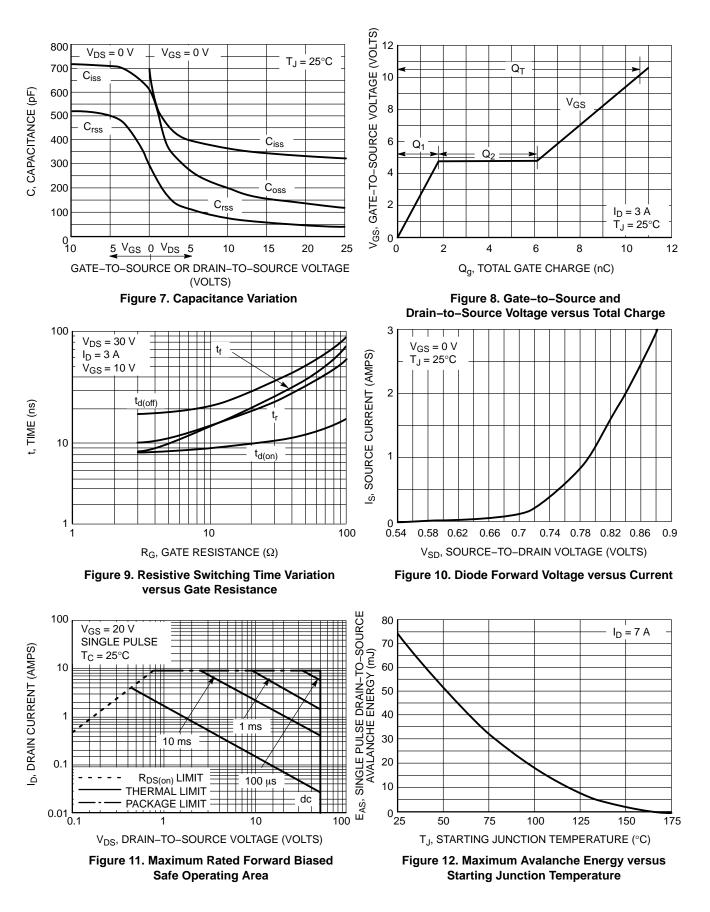
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Charac	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage ($V_{GS} = 0 Vdc$, $I_D = 250 \mu Adc$) Temperature Coefficient (Positive)	V _{(BR)DSS}	60 -	68 66		Vdc mV/°C	
Zero Gate Voltage Drain Current (V _{DS} = 60 Vdc, V _{GS} = 0 Vdc)	o Gate Voltage Drain Current				1.0 10	μAdc
Gate-Body Leakage Current (V _{GS} = \pm 20 Vdc, V _{DS} = 0 Vdc)		I _{GSS}	-	-	± 100	nAdc
ON CHARACTERISTICS (Note 3)					1	•
Gate Threshold Voltage (Note 3) ($V_{DS} = V_{GS}$, $I_D = 250 \mu Adc$) Threshold Temperature Coefficient (N	V _{GS(th)}	2.0	3.0 6.6	4.0 _	Vdc mV/°C	
Static Drain-to-Source On-Resistant (V _{GS} = 10 Vdc, I _D = 1.5 Adc)	R _{DS(on)}	_	88	110	mΩ	
$\begin{array}{l} \mbox{Static Drain-to-Source On-Resistant} \\ (V_{GS} = 10 \mbox{ Vdc}, \mbox{ I}_{D} = 3.0 \mbox{ Adc}) \\ (V_{GS} = 10 \mbox{ Vdc}, \mbox{ I}_{D} = 1.5 \mbox{ Adc}, \mbox{ T}_{J} = 0 \end{array}$	V _{DS(on)}	_	0.27 0.24	0.40 -	Vdc	
Forward Transconductance (Note 3) $(V_{DS} = 8.0 \text{ Vdc}, I_D = 1.7 \text{ Adc})$	9 _{fs}	-	3.2	-	Mhos	
DYNAMIC CHARACTERISTICS						
Input Capacitance		C _{iss}	-	324	455	pF
Output Capacitance	$(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0 \text{ V}, f = 1.0 \text{ MHz})$	C _{oss}	-	35	50	
Transfer Capacitance	r = 1.0 Wi12)	C _{rss}	-	110	155	
SWITCHING CHARACTERISTIC	6 (Note 4)	•				•
Turn-On Delay Time		t _{d(on)}	-	9.4	20	ns
Rise Time	$(V_{DD} = 30 \text{ Vdc}, I_D = 3.0 \text{ Adc},$	t _r	-	14	30	
Turn-Off Delay Time	V _{GS} = 10 Vdc, R _G = 9.1 Ω) (Note 3)	t _{d(off)}	-	21	45	
Fall Time		t _f	-	13	30	
Gate Charge	(V _{DS} = 48 Vdc, I _D = 3.0 Adc, V _{GS} = 10 Vdc) (Note 3)	QT	-	10.6	22	nC
		Q ₁	-	1.9	-	
		Q ₂	-	4.2	-	
SOURCE-DRAIN DIODE CHARA	CTERISTICS					
Forward On–Voltage		V _{SD}		0.89 0.74	1.0 _	Vdc
Reverse Recovery Time		t _{rr}	-	30	_	ns
	(I _S = 3.0 Adc, V _{GS} = 0 Vdc,	ta	-	22	_	1
	$dI_{S}/dt = 100 \text{ A}/\mu\text{s}$ (Note 3)	t _b	-	8.6	-	1
Reverse Recovery Stored Charge	Q _{RR}	-	0.04	_	μC	

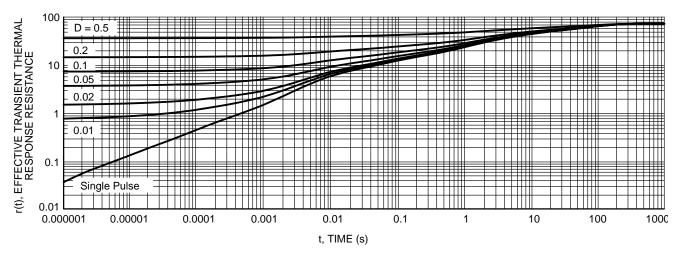
Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.
Switching characteristics are independent of operating junction temperatures.

NTF3055-100, NVF3055-100





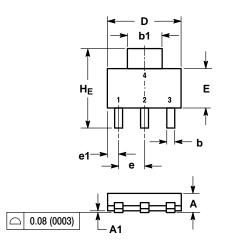
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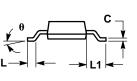




PACKAGE DIMENSIONS

SOT-223 (TO-261) CASE 318E-04 ISSUE N



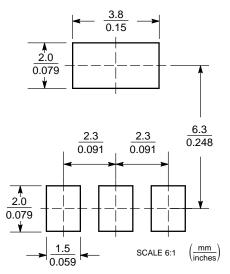


NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
С	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
Е	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L	0.20			0.008		
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
θ		_			-	

PIN 1. GATE 2. DRAIN 10° 0° 10° 3. SOURCE 4. DRAIN

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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